Storage Temperature Range



EMS22 C H E -33.333M

Series

RoHS Compliant (Pb-free) 4 Pad 3.2mm x 5mm SMD
2.5Vdc LVCMOS MEMS Spread Spectrum Oscillator

Frequency Tolerance/Stability ±100ppm Maximum over -20°C to +70°C

Output Control Function — Tri-State (Disabled Output High Impedance)

-55°C to +125°C

Nominal Frequency 33.333MHz

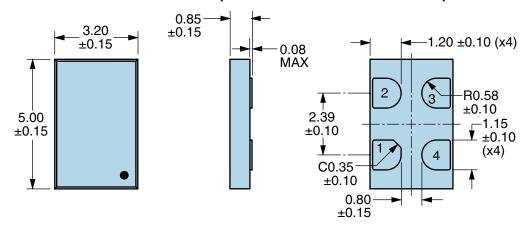
Spread Spectrum
-1.00% Down Spread

ELECTRICAL SPECIFICATIONS				
Nominal Frequency	33.333MHz			
Frequency Tolerance/Stability	±100ppm Maximum over -20°C to +70°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration)			
Aging at 25°C	±1ppm Maximum First Year			
Supply Voltage	2.5Vdc ±10%			
Maximum Supply Voltage	-0.5Vdc to +3.65Vdc			
Input Current	35mA Maximum (Unloaded; Nominal Vdd)			
Output Voltage Logic High (Voh)	90% of Vdd Minimum (IOH=-8mA)			
Output Voltage Logic Low (Vol)	10% of Vdd Maximum (IOL=+8mA)			
Rise/Fall Time	2nSec Maximum (Measured from 20% to 80% of waveform)			
Duty Cycle	50 ±5(%) (Measured at 50% of waveform)			
Load Drive Capability	15pF Maximum			
Output Logic Type	CMOS			
Output Control Function	Tri-State (Disabled Output High Impedance)			
Tri-State Input Voltage (Vih and Vil)	70% of Vdd Minimum or No Connection to Enable Output, 30% of Vdd Maximum to Disable Output			
Disable Current	20mA Maximum (Disabled Output: High Impedance) (Pad 1=Ground)			
Spread Spectrum	-1.00% Down Spread			
Modulation Frequency	30kHz Minimum, 32kHz Typical, 35kHz Maximum			
Period Jitter	40pSec Maximum (Cycle to Cycle; Spread Spectrum-On; Fo=133.333M, Vdd=2.5Vdc)			
Start Up Time	10mSec Maximum			

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V	
Flammability	UL94-V0	
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G	
Moisture Resistance	MIL-STD-883, Method 1004	
Moisture Sensitivity Level	J-STD-020, MSL 1	
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003 (Pads on bottom of package only)	
Temperature Cycling	MIL-STD-883, Method 1010, Condition B	
Thermal Shock	MIL-STD-883, Method 1011, Condition B	
Vibration	MIL-STD-883, Method 2007, Condition A, 20G	



MECHANICAL DIMENSIONS (all dimensions in millimeters)

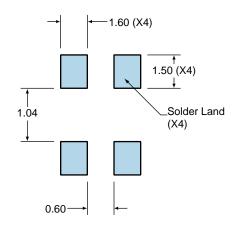


	PIN	CONNECTION
	1	Tri-State (High Impedance)
	2	Ground
	3	Output
Ì	4	Supply Voltage

LINE MARKING 1 XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code

Suggested Solder Pad Layout

All Dimensions in Millimeters



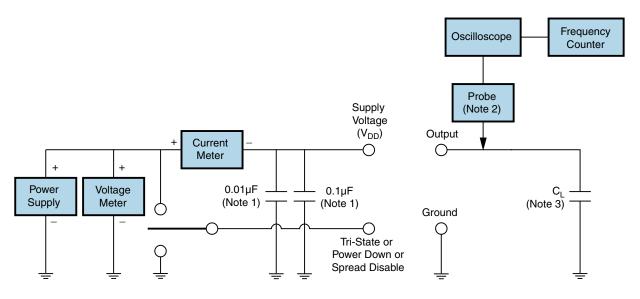
All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

T _s MAX to T _∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _s MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t _L)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t _p)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.